74LVC1G97

Low-power configurable multiple function gate

Rev. 2 — 9 March 2011

Product data sheet

1. General description

The 74LVC1G97 is a configurable multiple function gate with Schmitt-trigger inputs. The device can be configured as any of the following logic functions MUX, AND, OR, NAND, NOR, inverter and buffer; using the 3-bit input. All inputs can be connected to V_{CC} or GND.

Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in mixed 3.3 V and 5 V environments.

This device is fully specified for partial power-down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 1.65 V to 5.5 V
- 5 V tolerant input/output for interfacing with 5 V logic
- High noise immunity
- Complies with JEDEC standard:
 - ◆ JESD8-7 (1.65 V to 1.95 V)
 - ◆ JESD8-5 (2.3 V to 2.7 V)
 - ◆ JESD8B/JESD36 (2.7 V to 3.6 V).
- \pm 24 mA output drive (V_{CC} = 3.0 V)
- ESD protection:
 - ♦ HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
 - ◆ CDM JESD22-C101E exceeds 1000 V
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Inputs accept voltages up to 5 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C.



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3. Ordering information

Table 1. Ordering information

Type number	Package							
	Temperature range	Name	Description	Version				
74LVC1G97GW	-40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363				
74LVC1G97GV	–40 °C to +125 °C	SC-74	plastic surface mounted package; 6 leads	SOT457				
74LVC1G97GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1.45 \times 0.5 mm	SOT886				
74LVC1G97GF	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body $1 \times 1 \times 0.5$ mm	SOT891				
74LVC1G97GN	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm	SOT1115				
74LVC1G97GS	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $1.0 \times 1.0 \times 0.35$ mm	SOT1202				

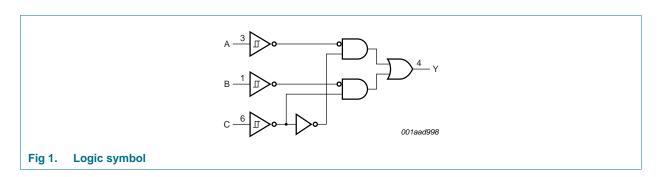
4. Marking

Table 2. Marking

Type number	Marking code[1]
74LVC1G97GW	YV
74LVC1G97GV	Y97
74LVC1G97GM	YV
74LVC1G97GF	YV
74LVC1G97GN	YV
74LVC1G97GS	YV

^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



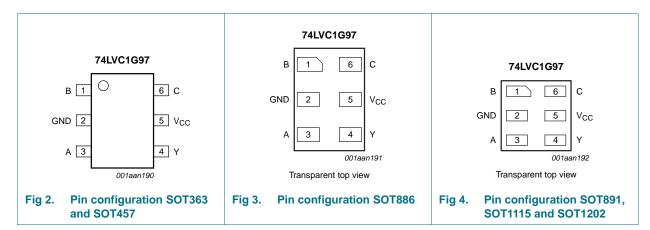
4LVC1G97

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6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
В	1	data input
GND	2	ground (0 V)
A	3	data input
Υ	4	data output
V _{CC}	5	supply voltage
С	6	data input

7. Functional description

Table 4. Function table[1]

Input			Output
С	В	Α	Υ
L	L	L	L
L	L	Н	L
L	Н	L	Н
L	Н	Н	Н
Н	L	L	L
Н	L	Н	Н
Н	Н	L	L
Н	Н	Н	Н

[1] H = HIGH voltage level; L = LOW voltage level.

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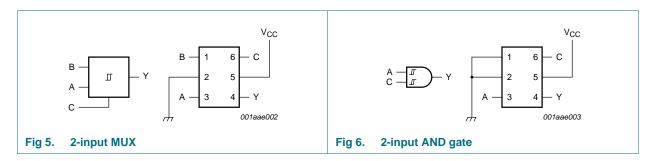
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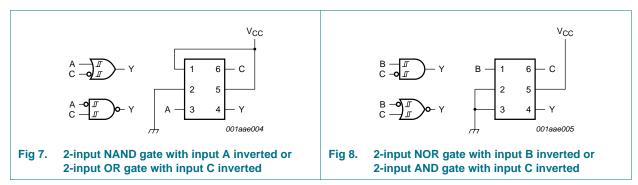
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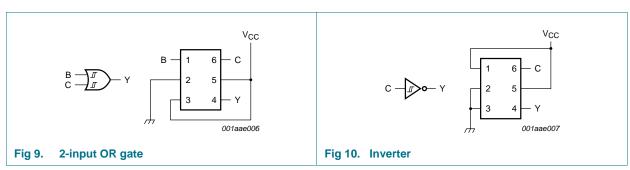
7.1 Logic configurations

Table 5. Function selection table

Logic function	Figure
2-input MUX	see Figure 5
2-input AND	see Figure 6
2-input OR with one input inverted	see Figure 7
2-input NAND with one input inverted	see Figure 7
2-input AND with one input inverted	see Figure 8
2-input NOR with one input inverted	see Figure 8
2-input OR	see Figure 9
Inverter	see Figure 10
Buffer	see Figure 11



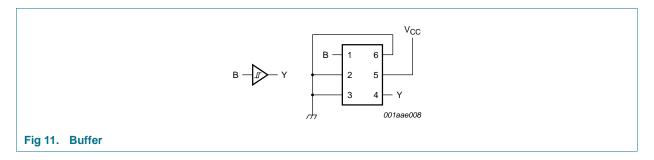




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8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

V_{CC} supply voltage $ I_{IK}$ input clamping current $V_I < 0 \text{ V}$ $-$	-0.5	Max +6.5	Unit V
I_{IK} input clamping current $V_I < 0 \text{ V}$		+6.5	V
			•
V ₁ input voltage [1] -	-50	-	mA
	-0.5	+6.5	V
I_{OK} output clamping current $V_O > V_{CC}$ or $V_O < 0 V$ -		±50	mA
V _O output voltage Active mode [1][2] –	-0.5	+6.5	V
Power-down mode [1][2] _	-0.5	+6.5	V
I_O output current $V_O = 0 \text{ V to } V_{CC}$ -		±50	mA
I _{CC} supply current -		+100	mA
I _{GND} ground current –	-100	-	mA
T _{stg} storage temperature –	-65	+150	°C
P_{tot} total power dissipation $T_{amb} = -40 ^{\circ}\text{C}$ to +125 $^{\circ}\text{C}$		250	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

9. Recommended operating conditions

Table 7. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage		1.65	-	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage	Active mode	0	-	V_{CC}	V
		V _{CC} = 0 V; Power-down mode	0	-	5.5	V
T_{amb}	ambient temperature		-40	-	+125	°C

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^[2] When $V_{CC} = 0 \text{ V}$ (Power-down mode), the output voltage can be 5.5 V in normal operation.

^[3] For SC-88 and SC-74 packages: above 87.5 $^{\circ}$ C the value of P_{tot} derates linearly with 4.0 mW/K. For XSON6 packages: above 118 $^{\circ}$ C the value of P_{tot} derates linearly with 7.8 mW/K.

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10. Static characteristics

Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	-40 °C to +85 °C			-40 °C to +125 °C	
			Min	Typ[1]	Max	Min	Max	
V _{OL} LOW-level output voltage	V _I = V _{CC} or GND	'		'			'	
	$I_O = 100 \mu A;$ $V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$	-	-	0.1	-	0.1	V	
		$I_O = 4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	-	-	0.45	-	0.7	V
		$I_{O} = 8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.3	-	0.45	V
		$I_O = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	-	-	0.4	-	0.6	V
		$I_O = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.55	-	0.8	V
		$I_O = 32 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.55	-	0.8	V
V _{OH}	HIGH-level	V _I = V _{CC} or GND						
	output voltage	$I_O = -100 \mu A;$ $V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$	V _{CC} - 0.1	-	-	V _{CC} – 0.1	-	V
		$I_{O} = -4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.2	-	-	0.95	-	V
		$I_{O} = -8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.9	-	-	1.7	-	V
		$I_{O} = -12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	2.2	-	-	1.9	-	V
		$I_{O} = -24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.3	-	-	2.0	-	V
		$I_{O} = -32 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.8	-	-	3.4	-	V
II	input leakage current	$V_I = 5.5 \text{ V or GND};$ $V_{CC} = 0 \text{ V to } 5.5 \text{ V}$	-	±0.1	±5	-	±100	μА
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 5.5 \text{ V}$; $V_{CC} = 0 \text{ V}$	-	±0.1	±10	-	±200	μА
I _{CC}	supply current	$V_I = 5.5 \text{ V or GND}; I_O = 0 \text{ A};$ $V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$	-	0.1	10	-	200	μА
ΔI_{CC}	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ $V_{CC} = 2.3 \text{ V} \text{ to } 5.5 \text{ V}$	-	5	500	-	5000	μА
C _I	input capacitance		-	2.5	-	-	-	pF

^[1] Typical values are measured at maximum V_{CC} and T_{amb} = 25 °C.

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11. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 13.

Symbol	Parameter	Conditions		–40 °C to +85 °C			-40 °C to +125 °C		Unit
				Min	Typ[1]	Max	Min	Max	
t_{pd}	propagation delay	A, B, C to Y; see Figure 12	[2]						
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		1.0	6.0	14.4	1.0	18.0	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.5	3.5	8.3	0.5	10.4	ns
		$V_{CC} = 2.7 \text{ V}$		0.5	4.2	8.5	0.5	10.6	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		0.5	3.8	6.3	0.5	7.9	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		0.5	3.0	5.1	0.5	6.4	ns
C _{PD}	power dissipation capacitance	V_{CC} = 3.3 V; V_I = GND to V_{CC}	[3]	-	22	-	-	-	pF

^[1] Typical values are measured at nominal V_{CC} and at T_{amb} = 25 °C.

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$$
 where:

 f_i = input frequency in MHz;

 f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

12. Waveforms

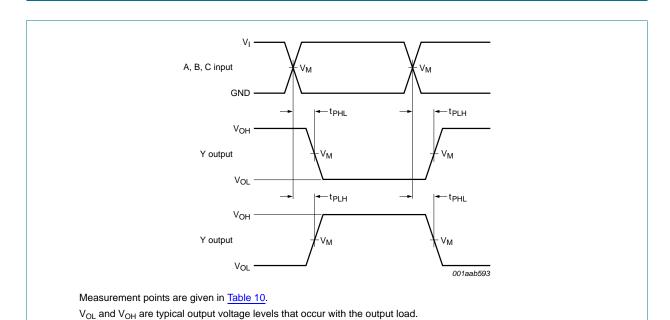


Fig 12. Input A, B and C to output Y propagation delay times

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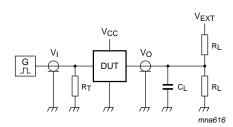
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^[2] t_{pd} is the same as t_{PLH} and t_{PHL}

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Table 10. Measurement points

Supply voltage	Input	Input	
V _{CC}	V _M	VI	V _M
1.65 V to 1.95 V	0.5V _{CC}	V _{CC}	0.5V _{CC}
2.3 V to 2.7 V	0.5V _{CC}	V _{CC}	0.5V _{CC}
2.7 V	1.5 V	2.7 V	1.5 V
3.0 V to 3.6 V	1.5 V	2.7 V	1.5 V
4.5 V to 5.5 V	0.5V _{CC}	V_{CC}	0.5V _{CC}



Measurement points are given in Table 11.

Definitions test circuit:

 R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig 13. Test circuit for measuring switching times

Table 11. Measurement points

Supply voltage	Input		Load	V _{EXT}	
V _{CC}	VI	$t_r = t_f$	CL	R _L	t _{PLH} , t _{PHL}
1.65 V to 1.95 V	V _{CC}	\leq 2.0 ns	30 pF	1 kΩ	open
2.3 to 2.7 V	V _{CC}	≤ 2.0 ns	30 pF	500 Ω	open
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open
4.5 V to 5.5 V	V _{CC}	≤ 2.5 ns	50 pF	500 Ω	open

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13. Transfer characteristics

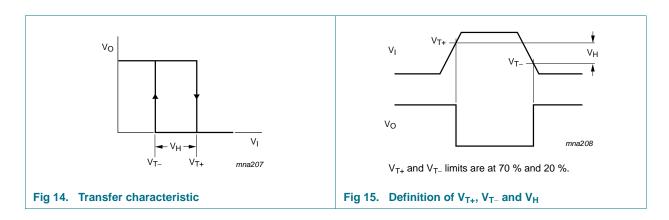
Table 12. Transfer characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-4	0 °C to +8	5 °C	-40 °C t	Unit	
			Min	Typ[1]	Max	Min	Max	
V _{T+} positive-going threshold voltage		see <u>Figure 14</u> , <u>Figure 15</u> , <u>Figure 16</u> and <u>Figure 17</u>						
		V _{CC} = 1.8 V	0.70	1.02	1.20	0.67	1.20	V
		V _{CC} = 2.3 V	1.11	1.42	1.60	1.08	1.60	V
		V _{CC} = 3.0 V	1.50	1.79	2.00	1.47	2.00	V
		V _{CC} = 4.5 V	2.16	2.52	2.74	2.13	2.74	V
		V _{CC} = 5.5 V	2.61	2.99	3.33	2.58	3.33	V
V_{T-}	negative-going threshold voltage	see Figure 14, Figure 15, Figure 16 and Figure 17						
		V _{CC} = 1.8 V	0.30	0.53	0.72	0.30	0.75	V
		V _{CC} = 2.3 V	0.58	0.77	1.00	0.58	1.03	V
		V _{CC} = 3.0 V	0.80	1.04	1.30	0.80	1.33	V
		V _{CC} = 4.5 V	1.21	1.55	1.90	1.21	1.93	V
		V _{CC} = 5.5 V	1.45	1.86	2.29	1.45	2.32	V
V _H	hysteresis voltage	(V _{T+} – V _{T-}). See Figure 14, Figure 15, Figure 16 and Figure 17						
		V _{CC} = 1.8 V	0.30	0.48	0.62	0.23	0.62	V
		V _{CC} = 2.3 V	0.40	0.64	0.80	0.34	0.80	V
		V _{CC} = 3.0 V	0.50	0.75	1.00	0.44	1.00	V
		V _{CC} = 4.5 V	0.71	0.97	1.20	0.65	1.20	V
		V _{CC} = 5.5 V	0.71	1.13	1.40	0.65	1.40	V

^[1] Typical values are measured at T_{amb} = 25 °C.

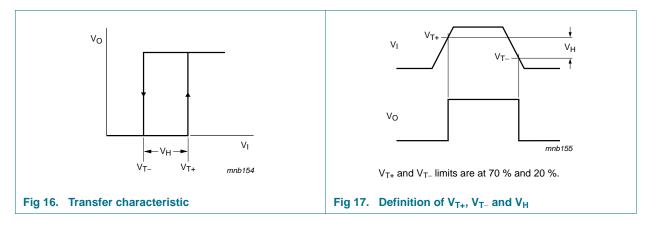
14. Waveforms transfer characteristics

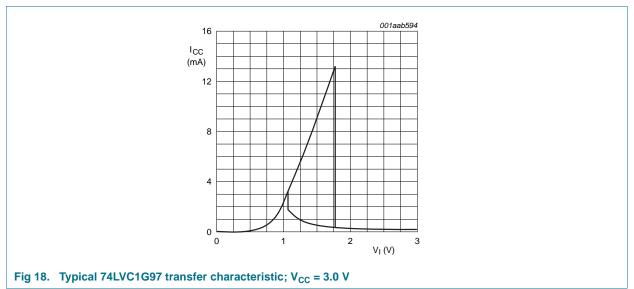


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15. Package outline

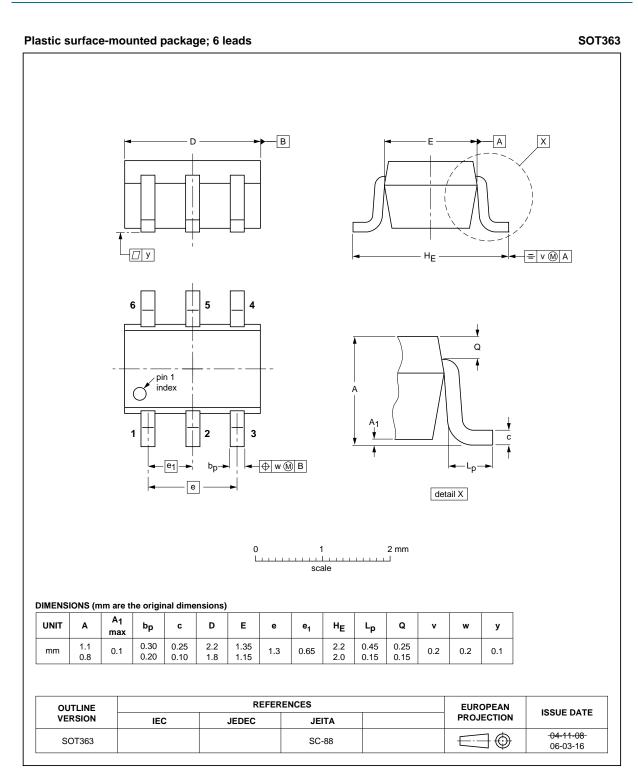


Fig 19. Package outline SOT363 (SC-88)

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Plastic surface-mounted package (TSOP6); 6 leads

SOT457

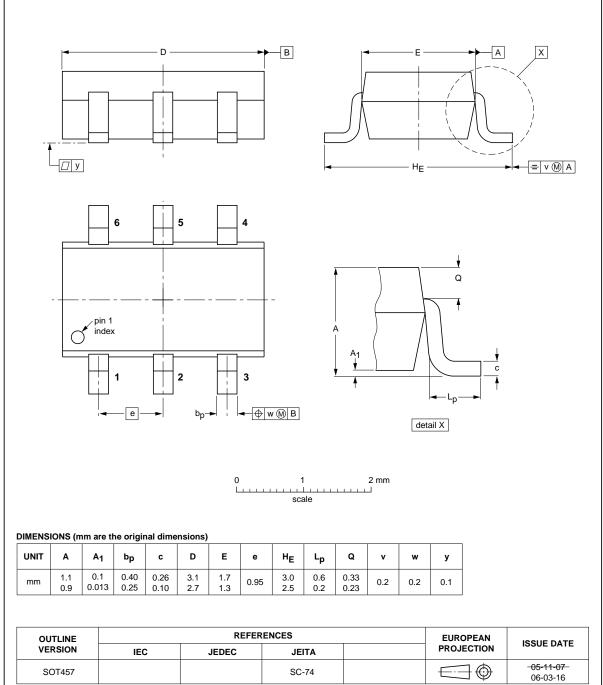


Fig 20. Package outline SOT457 (SC-74)

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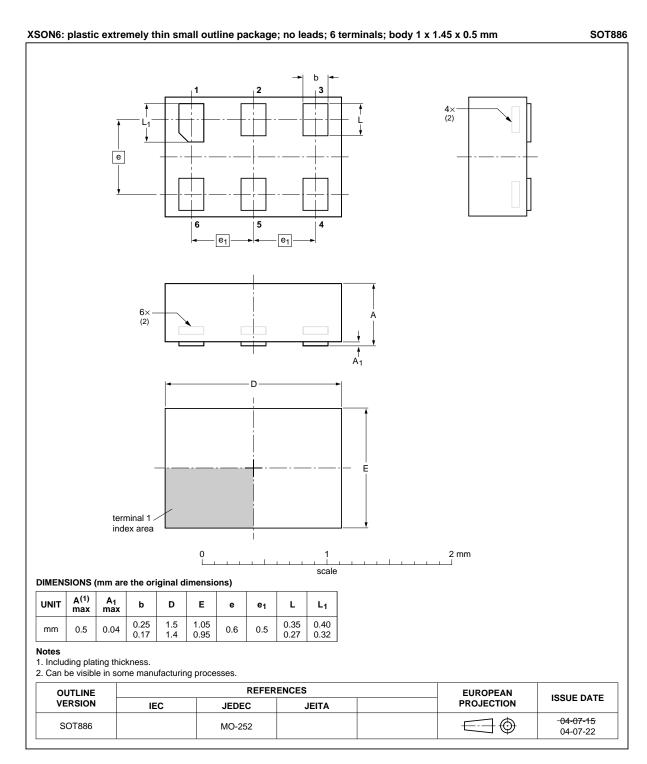


Fig 21. Package outline SOT886 (XSON6)

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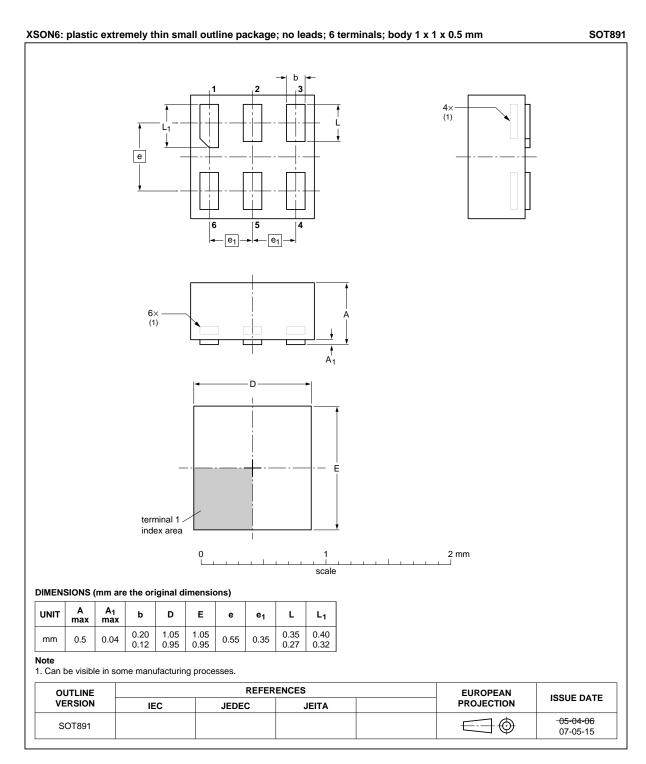


Fig 22. Package outline SOT891 (XSON6)

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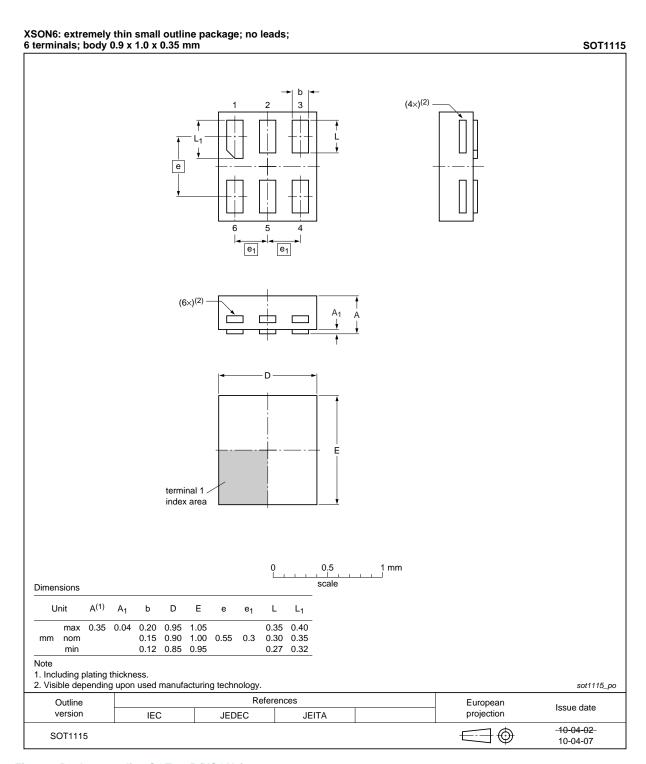


Fig 23. Package outline SOT1115 (XSON6)

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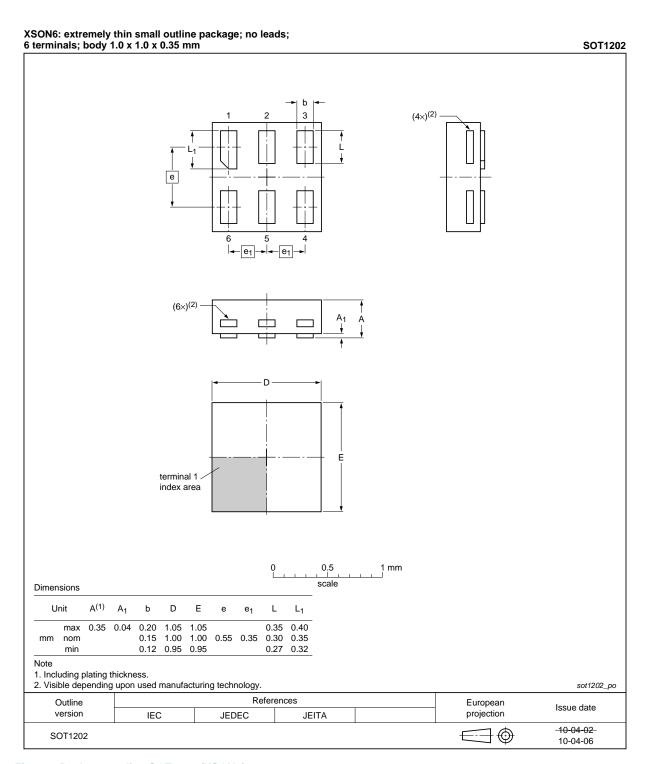


Fig 24. Package outline SOT1202 (XSON6)

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16. Abbreviations

Table 13. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal Oxide Semiconductor
TTL	Transistor-Transistor Logic
HBM	Human Body Model
ESD	ElectroStatic Discharge
MM	Machine Model
DUT	Device Under Test

17. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74LVC1G97 v.2	20110309	Product data sheet	-	74LVC1G97 v.1	
Modifications:	 <u>Table 2</u>: marking codes changed from V97 and VV to Y97 and YV. 				
74LVC1G97 v.1	20101221	Product data sheet	-	-	

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18. Legal information

18.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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